

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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PHOTOCOUPLER

PS2503-1,-2,-4,PS2503L-1,-2,-4

LOW INPUT CURRENT, HIGH SPEED SWITCHING MULTI PHOTOCOUPLER SERIES -NEPOC Series-

DESCRIPTION

The PS2503-1, -2, -4 and PS2503L-1, -2, -4 are optically coupled isolators containing a GaAs light emitting diode and an NPN silicon phototransistor.

The PS2503-1, -2, -4 are in a plastic DIP (Dual In-line Package) and the PS2503L-1, -2, -4 are lead bending type (Gull-wing) for surface mount.

FEATURES

- High isolation voltage (BV = 5 000 Vr.m.s.)
- High-speed switching ($t_r = 20 \mu s$ TYP., $t_f = 30 \mu s$ TYP.)
- Ordering number of tape product: PS2503L-1-E3, E4, F3, F4, PS2503L-2-E3, E4
- Safety standards
 - UL approved: File No. E72422 (S)
 - · CSA approved: No. CA 101391

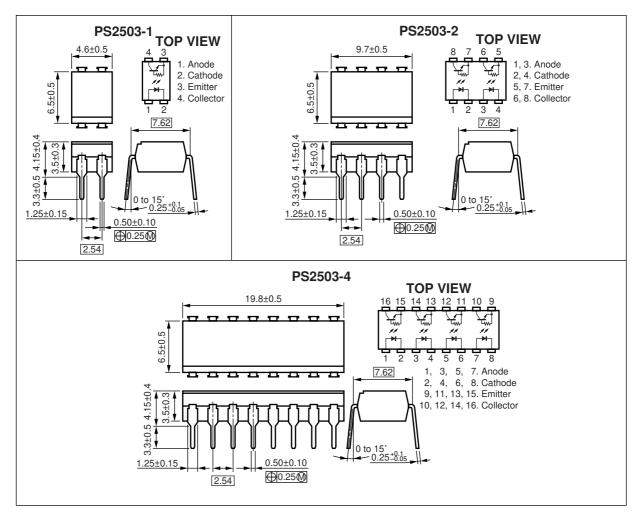
APPLICATIONS

- · Measurement equipment
- Programmable logic controller
- · Telephone/Telegraph Receiver
- · Power supply

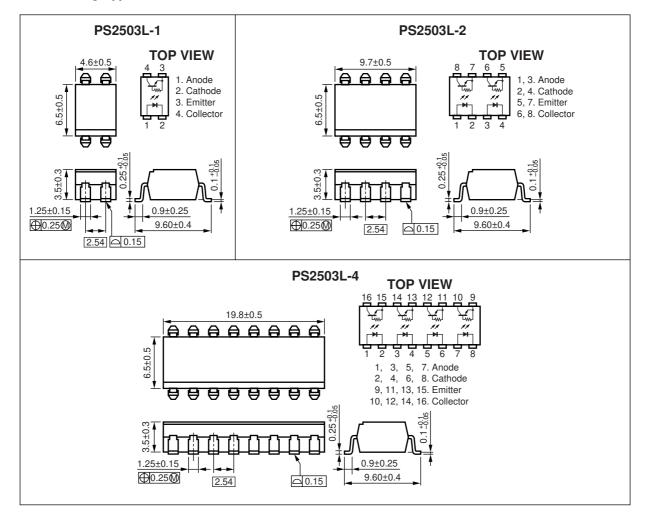
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★ PACKAGE DIMENSIONS (UNIT : mm)

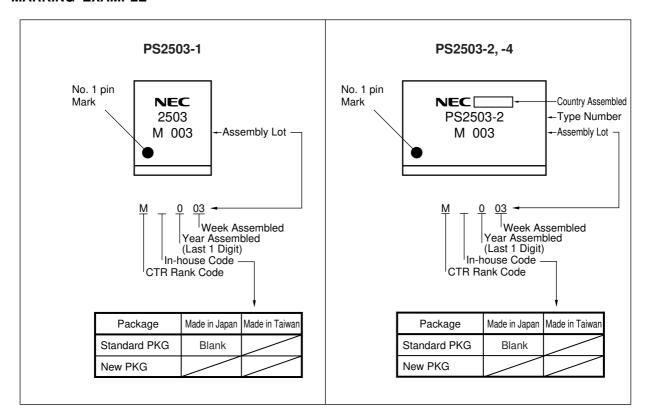
DIP Type



Lead Bending Type



MARKING EXAMPLE



ORDERING INFORMATION (Solder Contains Lead)

Part Number	Package	Packing Style	Application Part Number*1
PS2503-1	4-pin DIP	Magazine case 100 pcs	PS2503-1
PS2503L-1			
PS2503L-1-E3		Embossed Tape 1 000 pcs/reel	
PS2503L-1-E4			
PS2503L-1-F3		Embossed Tape 2 000 pcs/reel	
PS2503L-1-F4			
PS2503-2	8-pin DIP	Magazine case 45 pcs	PS2503-2
PS2503L-2			
PS2503L-2-E3		Embossed Tape 1 000 pcs/reel	
PS2503L-2-E4			
PS2503-4	16-pin DIP	Magazine case 20 pcs	PS2503-4
PS2503L-4			

^{*1} For the application of the Safety Standard, following part number should be used.

ORDERING INFORMATION (Pb-Free)

Part Number	Package	Packing Style	Application Part Number*1
PS2503-1-A	4-pin DIP	Magazine case 100 pcs	PS2503-1
PS2503L-1-A			
PS2503L-1-E3-A		Embossed Tape 1 000 pcs/reel	
PS2503L-1-E4-A			
PS2503L-1-F3-A		Embossed Tape 2 000 pcs/reel	
PS2503L-1-F4-A			
PS2503-2-A	8-pin DIP	Magazine case 45 pcs	PS2503-2
PS2503L-2-A			
PS2503L-2-E3-A		Embossed Tape 1 000 pcs/reel	
PS2503L-2-E4-A			
PS2503-4-A	16-pin DIP	Magazine case 20 pcs	PS2503-4
PS2503L-4-A			

^{*1} For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (TA = 25 °C, unless otherwise specified)

Parameter			Rati		
		Symbol	PS2503-1, PS2503L-1	PS2503-2,-4 PS2503L-2,-4	Unit
Diode	Reverse Voltage	VR	(3	V
	Forward Current (DC)	lF	8	0	mA
	Power Dissipation Derating	⊿P _D /°C	1.5	1.2	mW/°C
	Power Dissipation	PD	150	120	mW/ch
	Peak Forward Current*1	IFP	1		Α
Transistor	Collector to Emitter Voltage	VCEO	40		V
	Emitter to Collector Voltage	VECO	0.6		V
	Collector Current	lc	30		mA/ch
	Power Dissipation Derating	⊿Pc/°C	1.5	1.2	mW/°C
	Power Dissipation	Pc	150	120	mW/ch
Isolation Voltage*2		BV	5 000		Vr.m.s.
Operating Ambient Temperature		TA	-55 to +100		°C
Storage Temperature		T _{stg}	-55 to +150		°C

^{*1} PW = 100 μ s, Duty Cycle = 1 %

^{*2} AC voltage for 1 minute at $T_A = 25$ °C, RH = 60 % between input and output

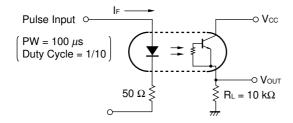
ELECTRICAL CHARACTERISTICS (TA = 25 °C)

	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	VF	IF = 1 mA		1.1	1.3	٧
	Reverse Current	lR	V _R = 5 V			5	μА
	Terminal Capacitance	Ct	V = 0 V, f = 1.0 MHz		50		pF
Transistor	Collector to Emitter Dark Current	ICEO	VcE = 40 V, IF = 0 mA			100	nA
Coupled	Current Transfer Ratio	CTR	IF = 1 mA, VcE = 5 V	100	200	400	%
	Collector Saturation Voltage	V _{CE(sat)}	IF = 1 mA, Ic = 0.2 mA			0.25	V
	Isolation Resistance	R _{I-O}	Vi-o = 1.0 kVpc	10 ¹¹			Ω
	Isolation Capacitance	C _{I-O}	V = 0 V, f = 1.0 MHz		0.5		pF
	Rise Time*2	tr	$Vcc = 5 \text{ V}, \text{ If } = 1 \text{ mA}, \text{ RL} = 10 \text{ k}\Omega$		20		μS
	Fall Time*2	tf			30		

*1 CTR rank (only PS2503-1, PS2503L-1)

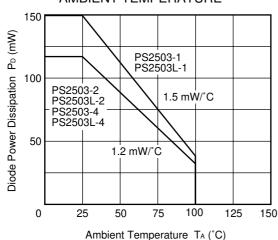
K : 200 to 400 (%) L : 150 to 300 (%) M : 100 to 200 (%)

*2 Test circuit for switching time

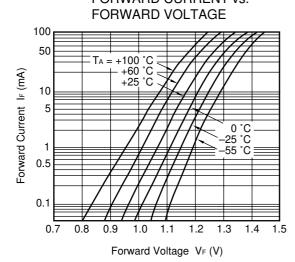


TYPICAL CHARACTERISTICS (TA = 25 °C, unless otherwise specified)

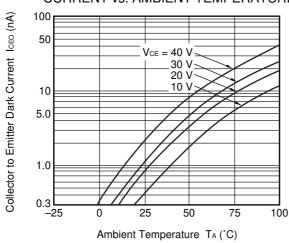




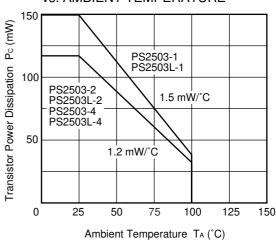
FORWARD CURRENT vs.



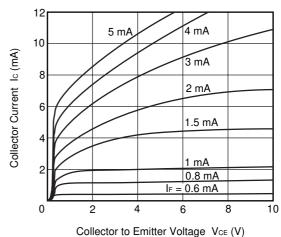
COLLECTOR TO EMITTER DARK CURRENT vs. AMBIENT TEMPERATURE



TRANSISTOR POWER DISSIPATION vs. AMBIENT TEMPERATURE

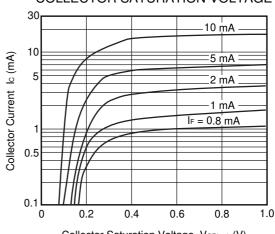


COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



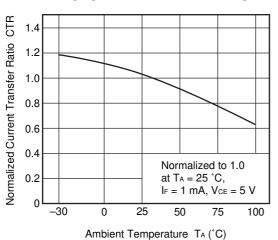
Collector to Emitter voltage VCE (V)

COLLECTOR CURRENT vs. COLLECTOR SATURATION VOLTAGE

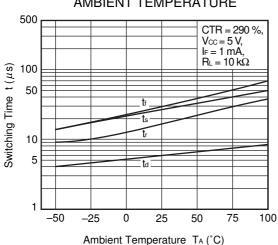


Collector Saturation Voltage VCE(sat) (V)

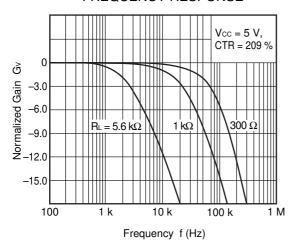
NORMALIZED CURRENT TRANSFER RATIO vs. AMBIENT TEMPERATURE



SWITCHING TIME vs. AMBIENT TEMPERATURE

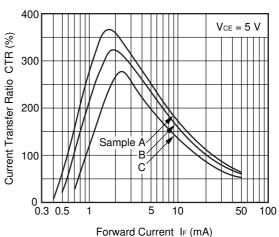


FREQUENCY RESPONSE

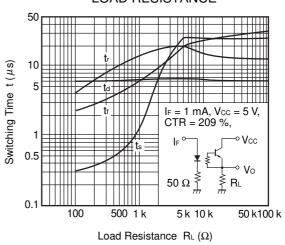


Remark The graphs indicate nominal characteristics.

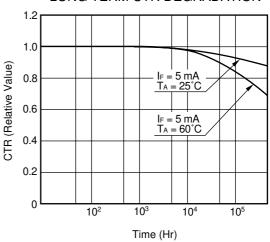
CURRENT TRANSFER RATIO vs. FORWARD CURRENT



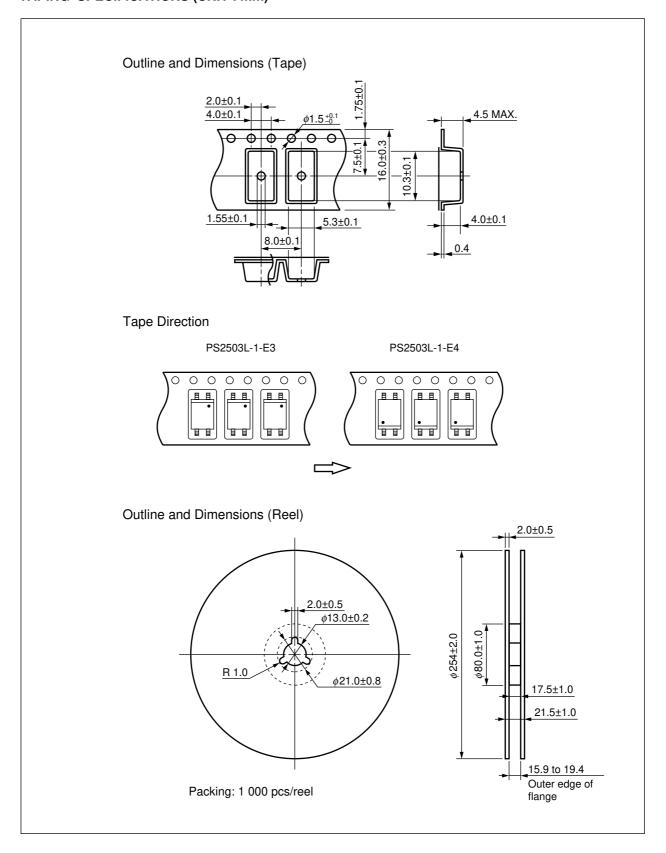
SWITCHING TIME vs. LOAD RESISTANCE

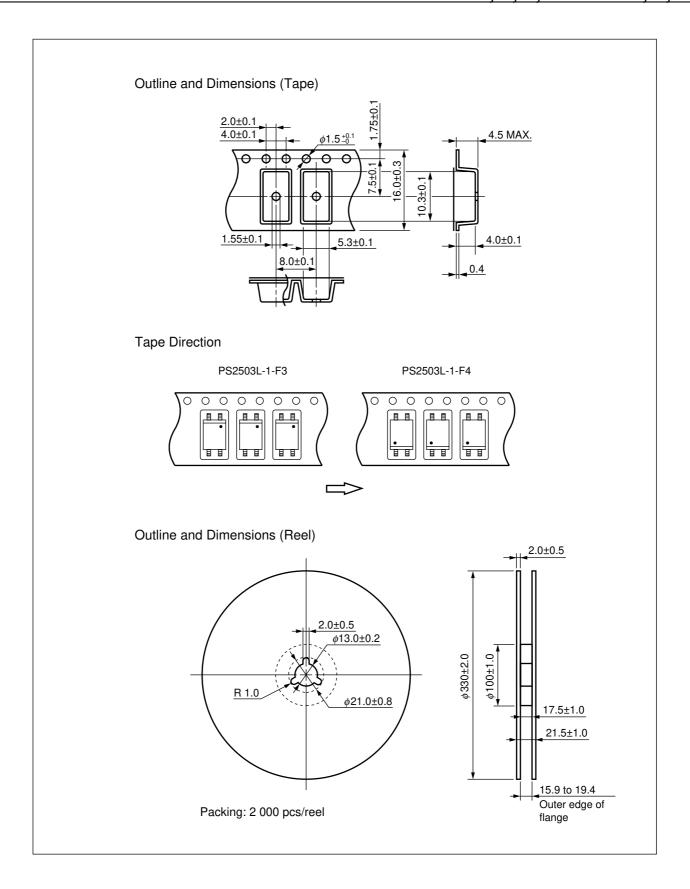


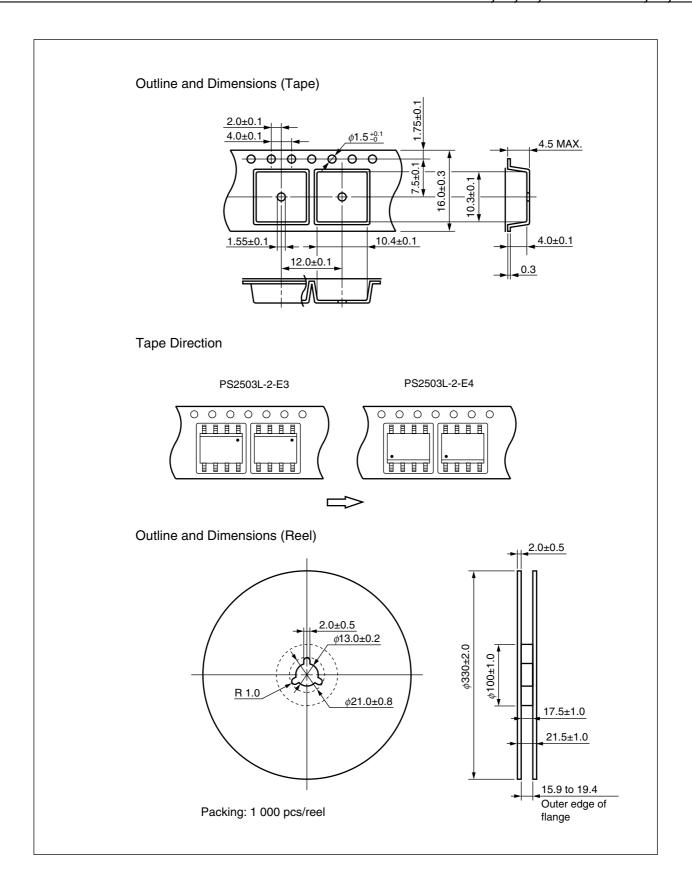
LONG TERM CTR DEGRADATION



* TAPING SPECIFICATIONS (UNIT: mm)







NOTES ON HANDLING

1. Recommended soldering conditions

(1) Infrared reflow soldering

· Peak reflow temperature 260°C or below (package surface temperature)

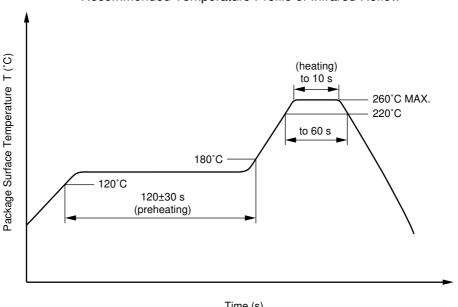
· Time of peak reflow temperature 10 seconds or less • Time of temperature higher than 220°C 60 seconds or less

• Time to preheat temperature from 120 to 180°C 120±30 s · Number of reflows Three

• Flux Rosin flux containing small amount of chlorine (The flux with a

maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



Time (s)

(2) Wave soldering

 Temperature 260°C or below (molten solder temperature)

• Time 10 seconds or less

· Preheating conditions 120°C or below (package surface temperature)

· Number of times One (Allowed to be dipped in solder including plastic mold portion.)

Rosin flux containing small amount of chlorine (The flux with a maximum chlorine • Flux

content of 0.2 Wt% is recommended.)

(3) Cautions

Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output or between collector-emitters at startup, the output side may enter the on state, even if the voltage is within the absolute maximum ratings.

★ USAGE CAUTIONS

- 1. Protect against static electricity when handling.
- 2. Avoid storage at a high temperature and high humidity.



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Subject: Compliance with EU Directives

CEL certifies, to its knowledge, that semiconductor and laser products detailed below are compliant with the requirements of European Union (EU) Directive 2002/95/EC Restriction on Use of Hazardous Substances in electrical and electronic equipment (RoHS) and the requirements of EU Directive 2003/11/EC Restriction on Penta and Octa BDE.

CEL Pb-free products have the same base part number with a suffix added. The suffix –A indicates that the device is Pb-free. The –AZ suffix is used to designate devices containing Pb which are exempted from the requirement of RoHS directive (*). In all cases the devices have Pb-free terminals. All devices with these suffixes meet the requirements of the RoHS directive.

This status is based on CEL's understanding of the EU Directives and knowledge of the materials that go into its products as of the date of disclosure of this information.

Restricted Substance per RoHS	Concentration Limit per RoHS (values are not yet fixed)		on contained devices	
Lead (Pb)	< 1000 PPM	-A Not Detected	-AZ (*)	
Mercury	< 1000 PPM	Not Detected		
Cadmium	< 100 PPM	Not Detected		
Hexavalent Chromium	< 1000 PPM	Not Detected		
PBB	< 1000 PPM	Not Detected		
PBDE	< 1000 PPM	Not Detected		

If you should have any additional questions regarding our devices and compliance to environmental standards, please do not hesitate to contact your local representative.

Important Information and Disclaimer: Information provided by CEL on its website or in other communications concerting the substance content of its products represents knowledge and belief as of the date that it is provided. CEL bases its knowledge and belief on information provided by third parties and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. CEL has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. CEL and CEL suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall CEL's liability arising out of such information exceed the total purchase price of the CEL part(s) at issue sold by CEL to customer on an annual basis.

See CEL Terms and Conditions for additional clarification of warranties and liability.